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**ON Semiconductor®** 



FDS4141 P-Channel PowerTrench<sup>®</sup> MOSFET

#### www.onsemi.com

### FDS4141 P-Channel PowerTrench<sup>®</sup> MOSFET -40V, -10.8A, 13.0m $\Omega$

#### Features

- Max  $r_{DS(on)}$  = 13.0m $\Omega$  at V<sub>GS</sub> = -10V, I<sub>D</sub> = -10.5A
- Max  $r_{DS(on)}$  = 19.0m $\Omega$  at V<sub>GS</sub> = -4.5V, I<sub>D</sub> = -8.4A
- High performance trench technology for extremely low r<sub>DS(on)</sub>
- RoHS Compliant

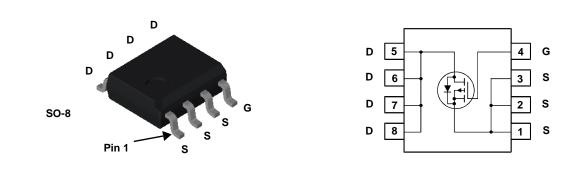


#### **General Description**

This P-Channel MOSFET has been produced using On Semiconductor's proprietary PowerTrench<sup>®</sup> technology to deliver low  $r_{DS(on)}$  and optimized  $BV_{DSS}$  capability to offer superior performance benefit in the applications and optimized switching performance capability reducing power dissipation losses in converter/inverter applications.

#### Applications

- Control switch in synchronous & non-synchronous buck
- Load switch
- Inverter



#### MOSFET Maximum Ratings T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V <sub>DS</sub>	Drain to Source Voltage		-40	V
V <sub>GS</sub>	Gate to Source Voltage		±20	V
ID	Drain Current -Continuous		-10.8	•
	-Pulsed		-36	- A
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 3)	294	mJ
P <sub>D</sub>	Power Dissipation $T_A = 25^{\circ}C$	(Note 1a)	5	W
	Power Dissipation $T_A = 25^{\circ}C$	(Note 1b)	2.5	vv
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range		-55 to +150	°C

#### **Thermal Characteristics**

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	(Note 1)	25	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	50	C/W

#### Package Marking and Ordering Information

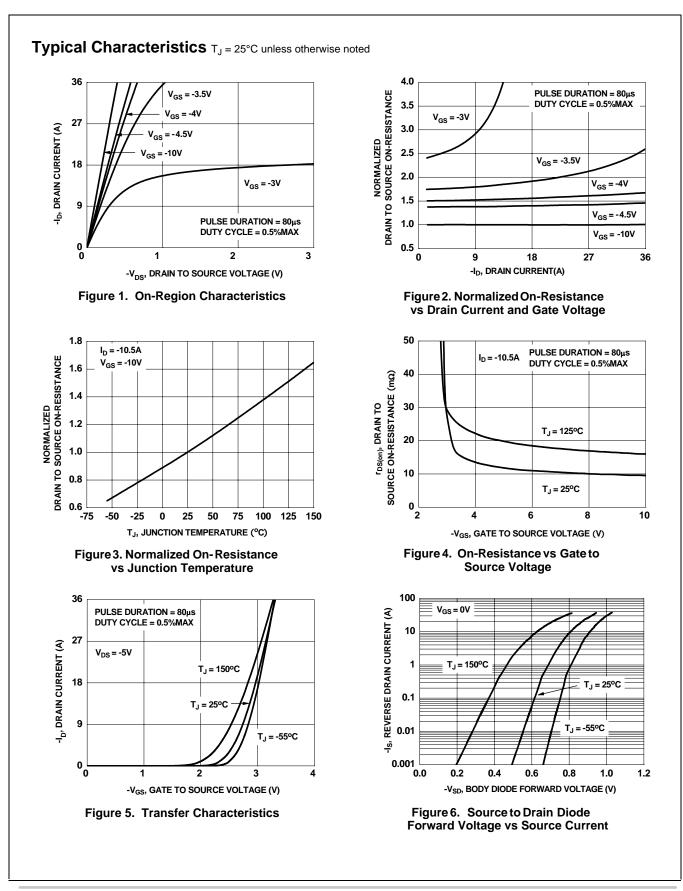
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS4141	FDS4141	SO-8	13"	12mm	2500units

Symbol	Parameter	Test Conditions		Min	Тур	Max	Units
Off Chara	cteristics						
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = -250μA, V <sub>GS</sub> = 0\	/	-40			V
$\Delta BV_{DSS} \Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = -250\mu$ A, referenced to 25°C			-33		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = -32V,				-1	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$	1			±100	nA
On Chara	cteristics	-				1	
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$\gamma = \gamma = -250$		-1.0	-1.6	-3.0	V
$\Delta V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = -250 \mu A$		1.0	1.0	-0.0	
$\Delta T_{J}$	Temperature Coefficient	$I_D = -250\mu A$ , referenced to 25°C			5.3		mV/°C
		$V_{GS} = -10V, I_D = -10.5A$			11.0	13.0	mΩ
r <sub>DS(on)</sub>	Static Drain to Source On Resistance	$V_{GS} = -4.5V, I_{D} = -8.4A$			15.2	19.0	
		$V_{GS} = -10V, I_D = -10.5A, T_J = 125^{\circ}C$			16.8	19.9	
9 <sub>FS</sub>	Forward Transconductance	$V_{DD} = -5V, I_D = -10.5A$			37		S
Dynamic	Characteristics						
C <sub>iss</sub>	Input Capacitance	$V_{DS} = -20V, V_{GS} = 0V,$ 			2005	2670	pF
C <sub>oss</sub>	Output Capacitance				355	475	pF
C <sub>rss</sub>	Reverse Transfer Capacitance				190	285	pF
R <sub>g</sub>	Gate Resistance	f = 1MHz			5		Ω
Switching	Characteristics				1	1	1
t <sub>d(on)</sub>	Turn-On Delay Time	$V_{DD} = -20V, I_D = -10.5A,$ $V_{GS} = -10V, R_{GEN} = 6\Omega$			10	20	ns
t <sub>r</sub>	Rise Time				5	10	ns
t <sub>d(off)</sub>	Turn-Off Delay Time				42	68	ns
t <sub>f</sub>	Fall Time				12	22	ns
Q <sub>g</sub>	Total Gate Charge	$V_{GS} = 0V \text{ to } -10V$	-		35	49	nC
Q <sub>g</sub>	Total Gate Charge		<sub>DD</sub> = -20V, <sub>0</sub> = -10.5A		19	27	nC
Q <sub>gs</sub>	Gate to Source Charge Gate to Drain "Miller" Charge	'	) = -10.5A		6 7		nC nC
Q <sub>gd</sub>					1		lic
Drain-Soເ	Irce Diode Characteristics				1		
V <sub>SD</sub>	Source to Drain Diode Forward Voltage	$V_{GS} = 0V, I_{S} = -10.5A$ $V_{GS} = 0V, I_{S} = -2.1A$	(Note 2) (Note 2)		-0.8 -0.7	-1.3 -1.2	V
t <sub>rr</sub>	Reverse Recovery Time				26	42	ns
Q <sub>rr</sub>	Reverse Recovery Charge	I <sub>F</sub> = -10.5A, di/dt = 100A/μs			14	26	nC
NOTES: 1. R <sub>0JA</sub> is determ the user's boa	ined with the device mounted on a 1in <sup>2</sup> pad 2 oz copper par rd design. a) 50°C/W when m 1in <sup>2</sup> pad of 2 oz	iounted on a	b) 12		en mounted o		termined b

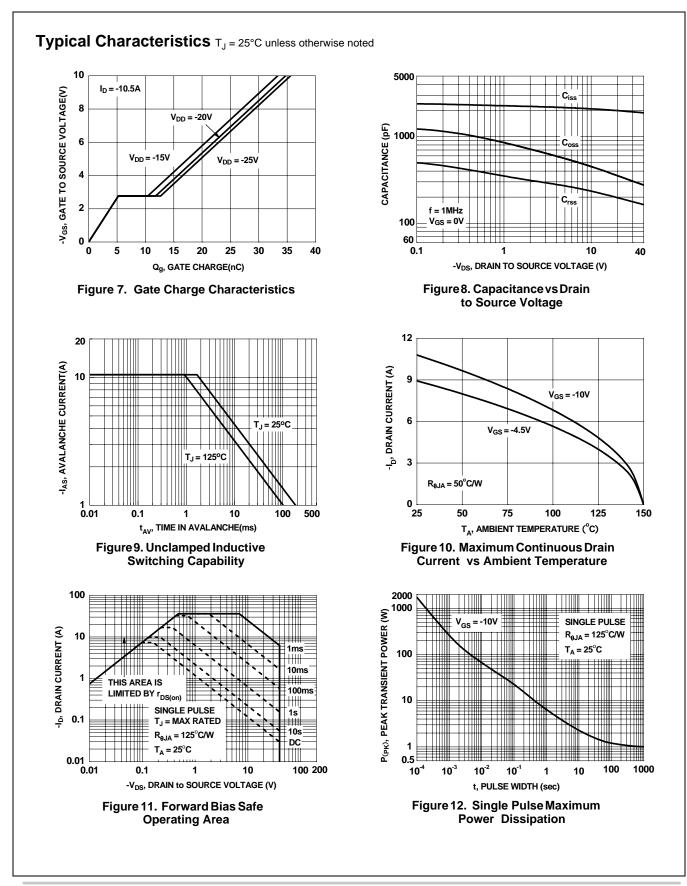
2. Pulse Test: Pulse Width < 300 $\mu s,$  Duty cycle < 2.0%.

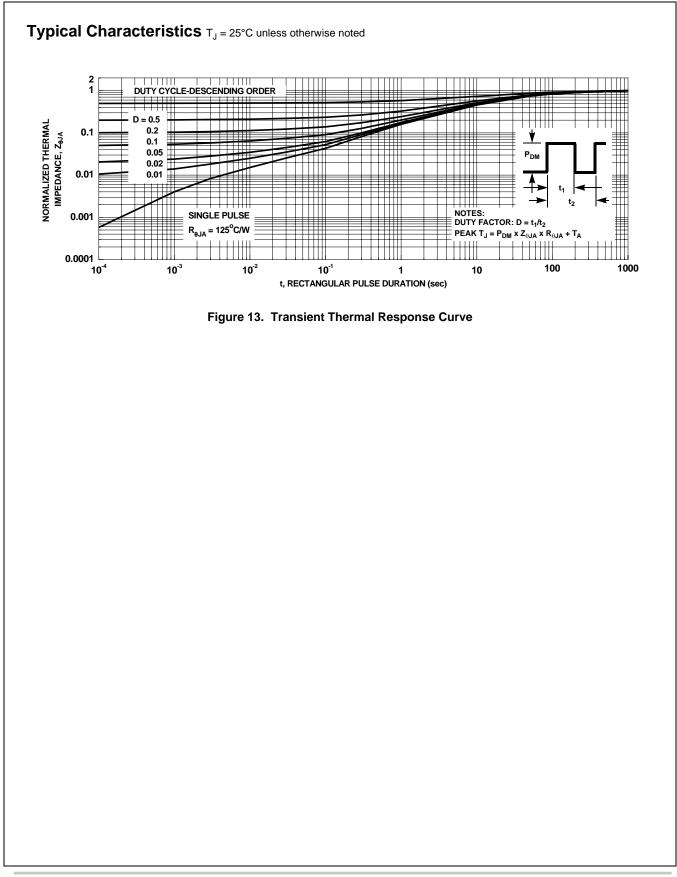
3. UIL condition: Starting  $T_J$  = 25°C, L = 3mH,  $I_{AS}$  = -14A,  $V_{DD}$  = -40V,  $V_{GS}$  = -10V.

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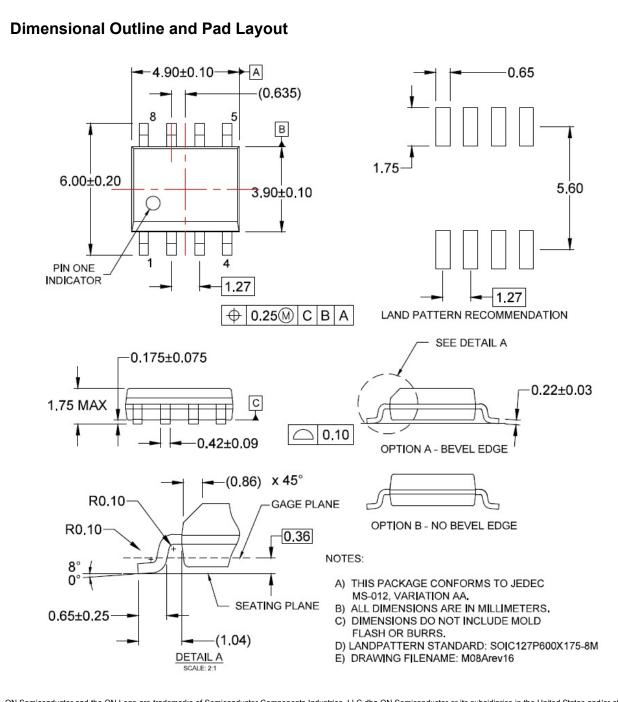








FDS4141 P-Channel PowerTrench<sup>®</sup> MOSFET



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